

N-Channel NexFET™ Power MOSFETs

 Check for Samples: [CSD16407Q5](#)

FEATURES

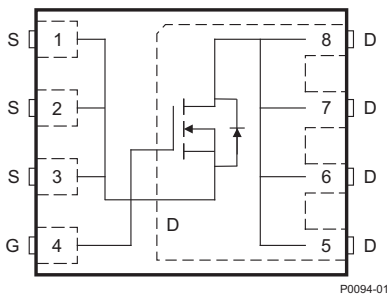
- **Ultralow Qg and Qgd**
- **Low Thermal Resistance**
- **Avalanche Rated**
- **SON 5-mm × 6-mm Plastic Package**

APPLICATIONS

- **Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems**
- **Optimized for Synchronous FET Applications**

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.

Top View


PRODUCT SUMMARY

V_{DS}	Drain-to-source voltage	25	V
Q_g	Gate charge, total (4.5 V)	13.3	nC
Q_{gd}	Gate charge, gate-to-drain	3.5	nC
$R_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 4.5\text{ V}$	2.5 mΩ
		$V_{GS} = 10\text{ V}$	1.8 mΩ
$V_{GS(th)}$	Threshold voltage	1.6	V

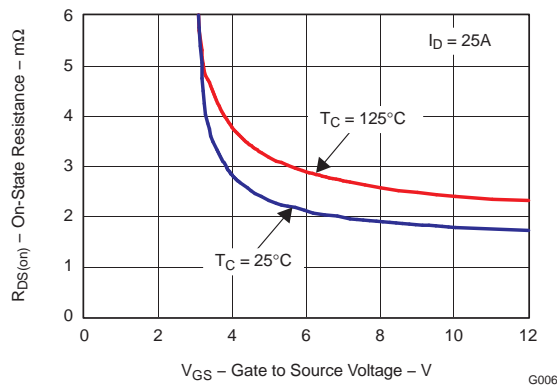
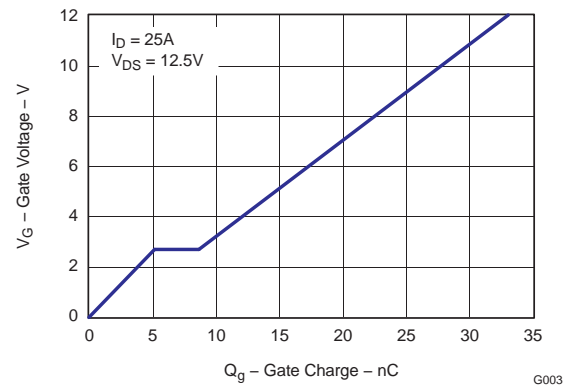
ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD16407Q5	SON 5 × 6 plastic package	13-inch reel	2500	Tape and reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain-to-source voltage	25	V
V_{GS}	Gate-to-source voltage	+16 / -12	V
I_D	Continuous drain current, $T_C = 25^\circ\text{C}$	100	A
	Continuous drain current ⁽¹⁾	31	A
I_{DM}	Pulsed drain current, $T_A = 25^\circ\text{C}$ ⁽²⁾	200	A
P_D	Power dissipation ⁽¹⁾	3.1	W
T_J , T_{STG}	Operating junction and storage temperature range	-55 to 150	°C
E_{AS}	Avalanche energy, single pulse $I_D = 66\text{ A}$, $L = 0.1\text{ mH}$, $R_G = 25\ \Omega$	218	mJ

- (1) $R_{\theta JA} = 40^\circ\text{C/W}$ on 1 in² (6.45 cm²) Cu [2 oz. (0.071 mm thick)] on 0.060-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

 $r_{DS(on)}$ vs V_{GS}

Gate Charge


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NexFET is a trademark of Texas Instruments.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
B _V DSS	Drain-to-source voltage	V _{GS} = 0 V, I _D = 250 μA	25			V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0 V, V _{DS} = 20 V			1	μA
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0 V, V _{GS} = 16 V to –12 V			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	V _{DS} = V _{GS} , I _D = 250 μA	1.3	1.6	1.9	V
r _{DS(on)}	Drain-to-source on-resistance	V _{GS} = 4.5 V, I _D = 25 A		2.5	3.3	mΩ
		V _{GS} = 10 V, I _D = 25 A		1.8	2.4	mΩ
g _{fs}	Transconductance	V _{DS} = 15 V, I _D = 25 A		111		S
Dynamic Characteristics						
C _{ISS}	Input capacitance	V _{GS} = 0 V, V _{DS} = 12.5 V, f = 1 MHz		2040	2660	pF
C _{OSS}	Output capacitance			1600	2080	pF
C _{RSS}	Reverse transfer capacitance			115	160	pF
R _g	Series gate resistance	V _{DS} = 12.5 V, I _D = 25 A		1.2	2.4	Ω
Q _g	Gate charge total (4.5 V)			13.3	18	nC
Q _{gd}	Gate charge, gate-to-drain			3.5		nC
Q _{gs}	Gate charge, gate-to-source			5.3		nC
Q _{g(th)}	Gate charge at V _{th}			3.1		nC
Q _{OSS}	Output charge	V _{DS} = 13.5 V, V _{GS} = 0 V		33		nC
t _{d(on)}	Turnon delay time	V _{DS} = 12.5 V, V _{GS} = 4.5 V, I _D = 25 A R _G = 2 Ω		11.9		ns
t _r	Rise time			18.4		ns
t _{d(off)}	Turnoff delay time			16		ns
t _f	Fall time			9		ns
Diode Characteristics						
V _{SD}	Diode forward voltage	I _S = 25 A, V _{GS} = 0 V		0.8	1	V
Q _{rr}	Reverse recovery charge	V _{DD} = 13.5 V, I _F = 25 A, di/dt = 300 A/μs		41		nC
t _{rr}	Reverse recovery time	V _{DD} = 13.5 V, I _F = 25 A, di/dt = 300 A/μs		34		ns

THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

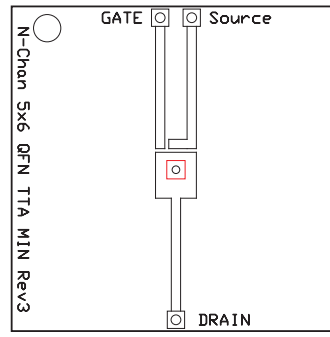
PARAMETER		MIN	TYP	MAX	UNIT
R _{θJC}	Thermal resistance, junction-to-case ⁽¹⁾			1.1	°C/W
R _{θJA}	Thermal resistance, junction-to-ambient ^{(1) (2)}			51	°C/W

- (1) R_{θJC} is determined with the device mounted on a 1-inch (2.54-cm) square 2-oz (0.071-mm thick) Cu pad on a 1.5-inch (3.81-cm) × 1.5-inch (3.81-cm) × 0.060-inch (1.52-mm) thick FR4 board. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
- (2) Device mounted on FR4 material with 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



M0137-01

Max $R_{\theta JA} = 50^{\circ}\text{C/W}$
when mounted on 1
 inch^2 (6.45 cm^2) of
2-oz. (0.071-mm thick)
Cu.

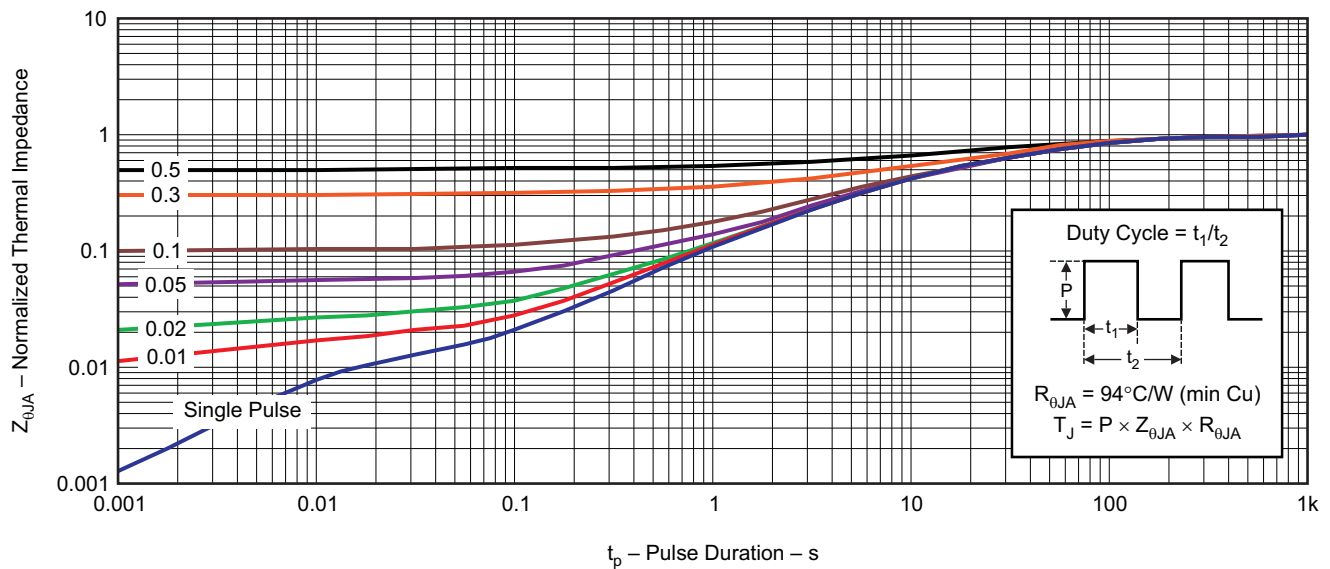


M0137-02

Max $R_{\theta JA} = 121^{\circ}\text{C/W}$
when mounted on
minimum pad area of
2-oz. (0.071-mm thick)
Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



G012

Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

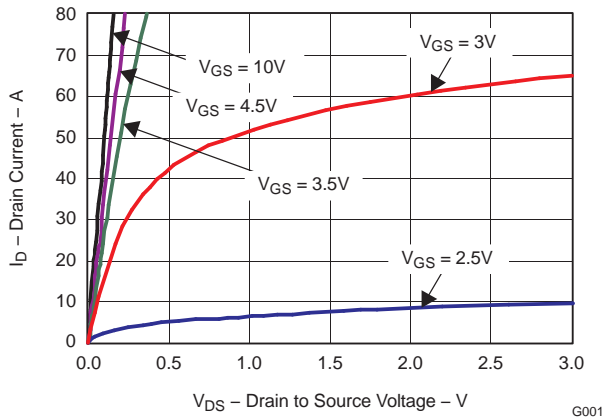


Figure 2. Saturation Characteristics

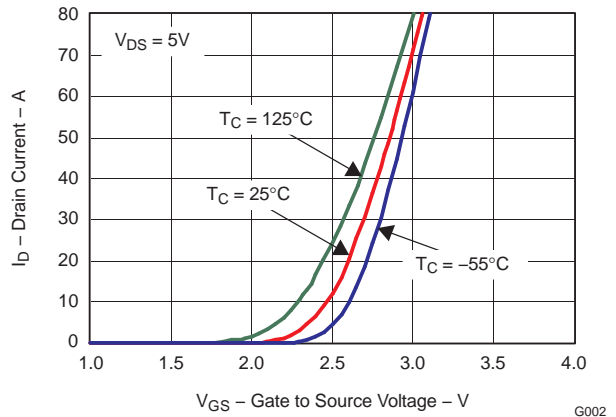


Figure 3. Transfer Characteristics

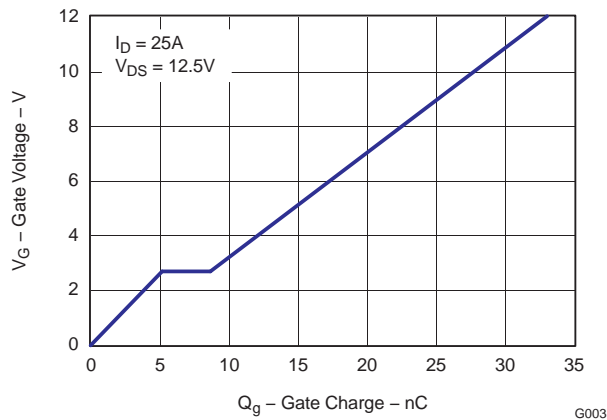


Figure 4. Gate Charge

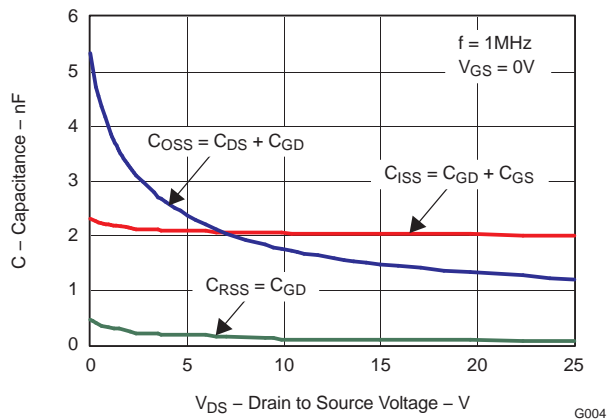


Figure 5. Capacitance

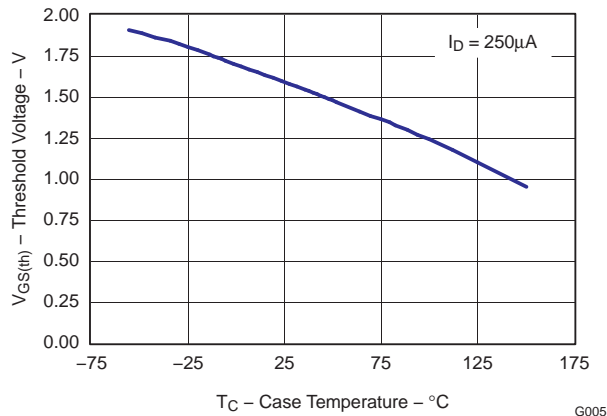


Figure 6. Threshold Voltage vs. Temperature

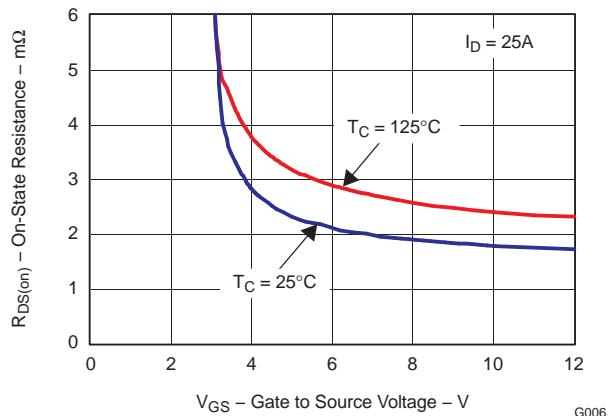


Figure 7. On Resistance vs. Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

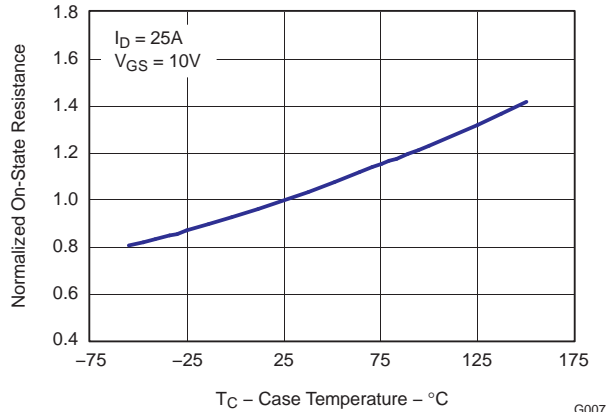


Figure 8. On Resistance vs. Temperature

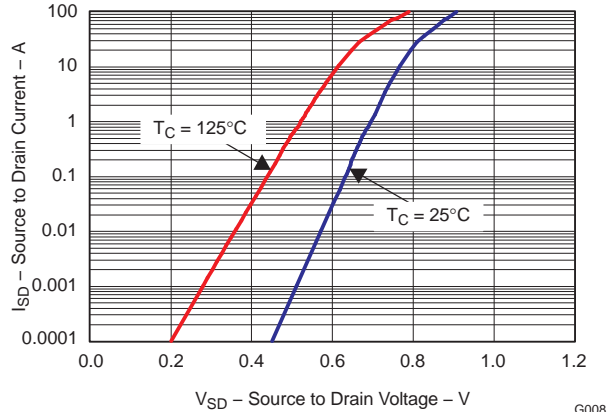


Figure 9. Typical Diode Forward Voltage

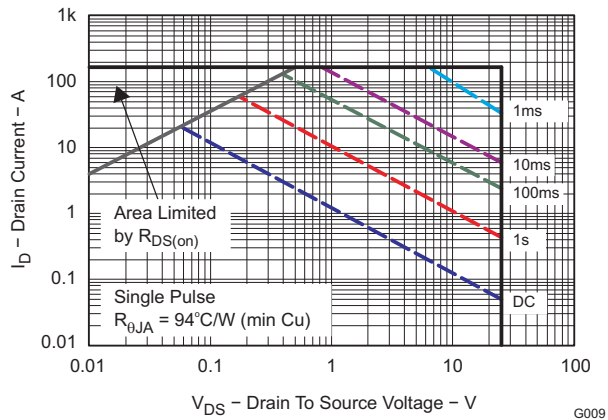


Figure 10. Maximum Safe Operating Area

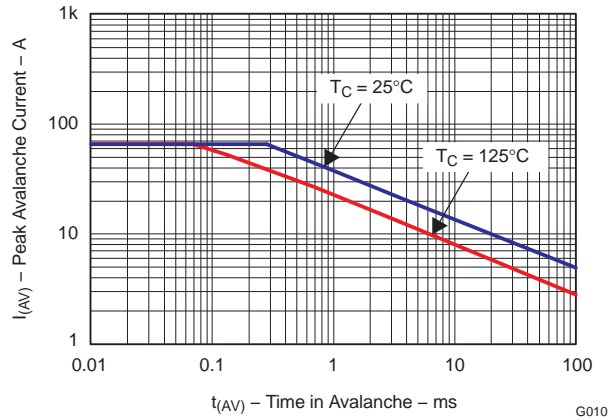


Figure 11. Single Pulse Unclamped Inductive Switching

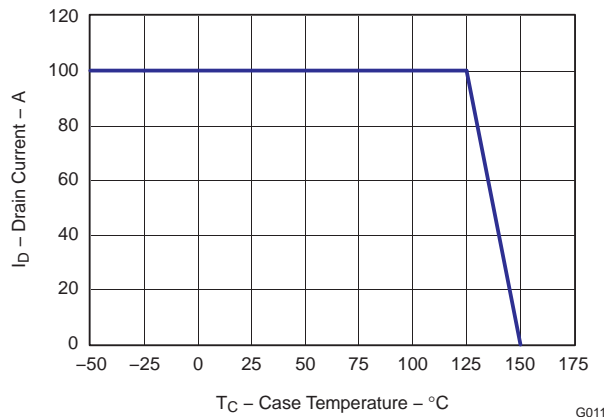
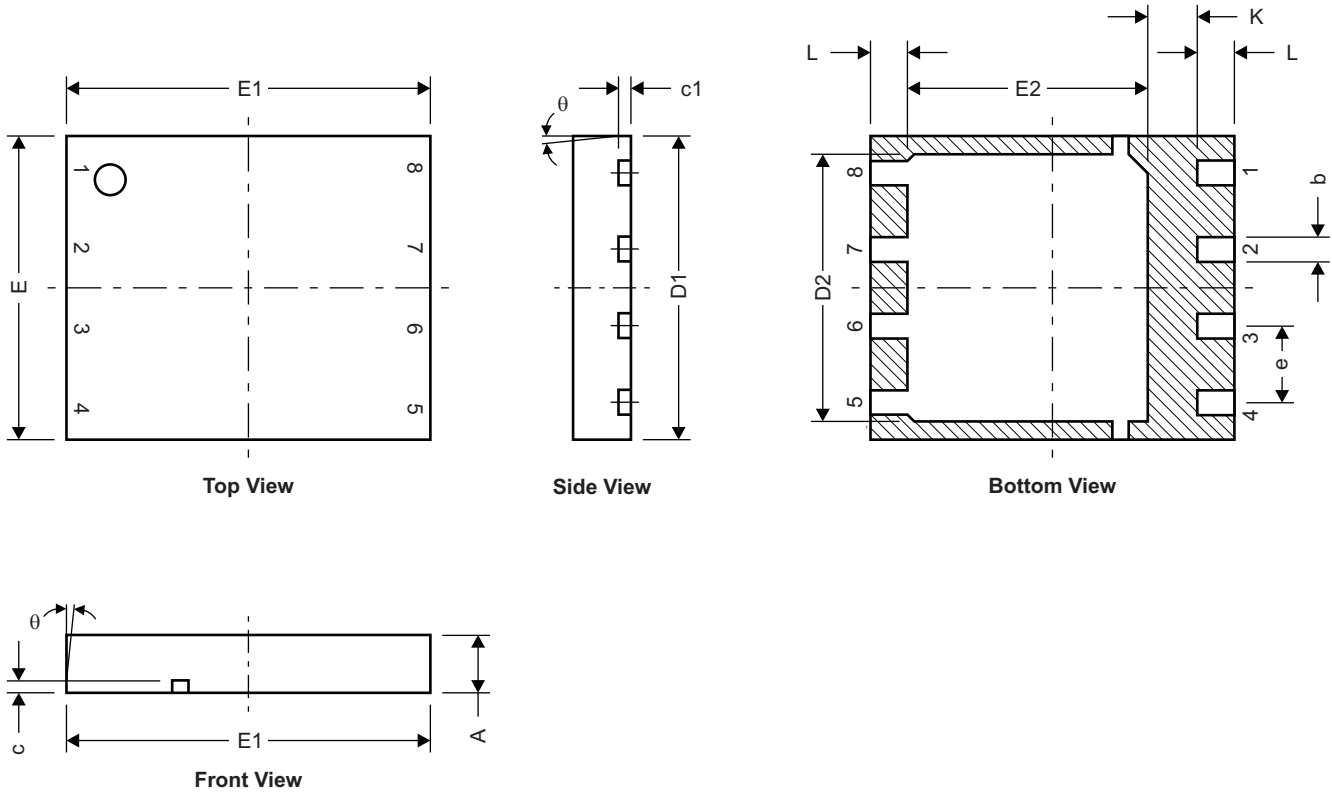


Figure 12. Maximum Drain Current vs. Temperature

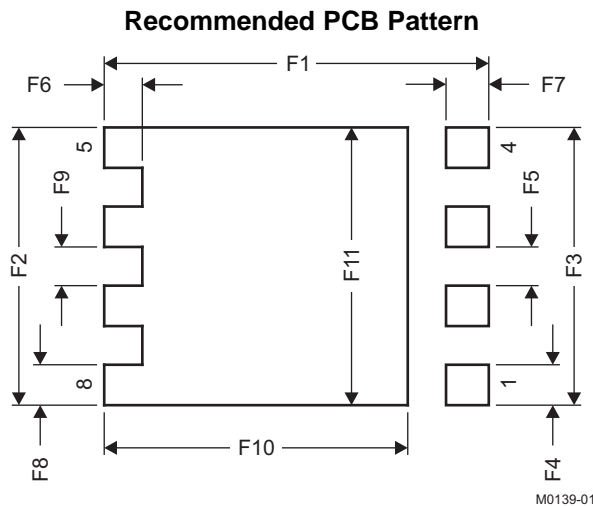
MECHANICAL DATA

Q5 Package Dimensions



M0140-01

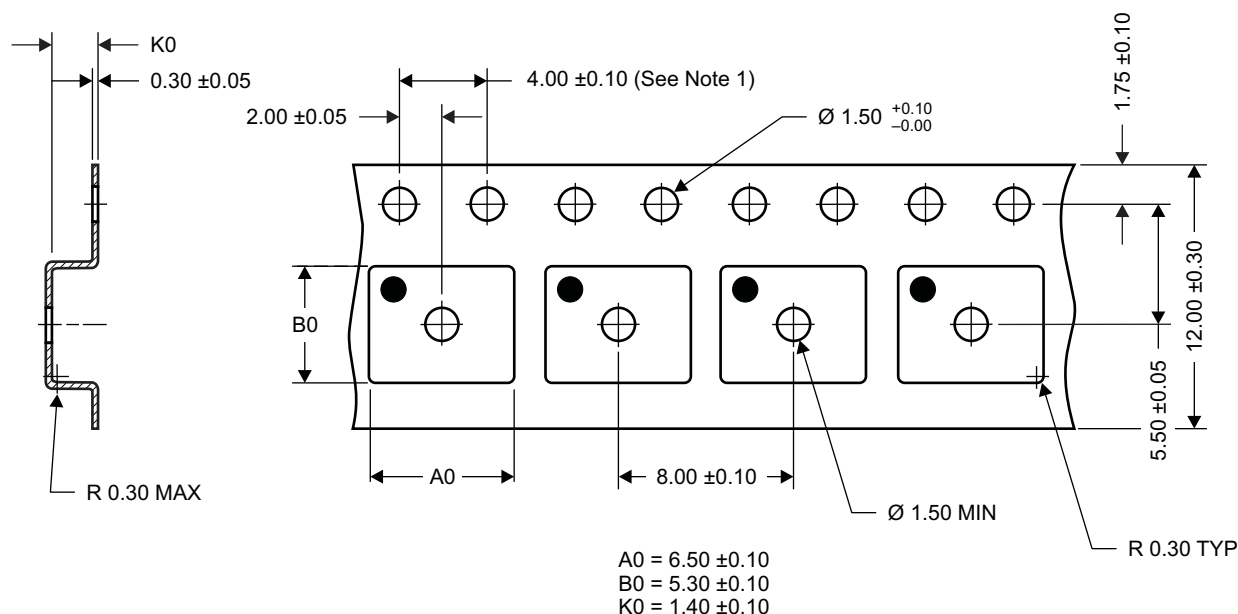
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
c	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
e	1.27 TYP		0.050	
L	0.510	0.710	0.020	0.028
theta	0.00	-	-	-
K	0.760	-	0.030	-



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.2440	0.248
F2	4.460	4.560	0.1760	0.180
F3	4.460	4.560	0.1760	0.180
F4	0.650	0.700	0.0260	0.028
F5	0.620	0.670	0.0240	0.026
F6	0.630	0.680	0.0250	0.027
F7	0.70	0.800	0.0380	0.031
F8	0.650	0.700	0.0260	0.028
F9	0.620	0.670	0.0240	0.026
F10	4.900	5.000	0.1930	0.197
F11	4.460	4.560	0.1760	0.180

For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing Through PCB Layout Techniques](#).

Q5 Tape and Reel Information



Notes:

- 10 sprocket hole pitch cumulative tolerance ± 0.2
- Camber not to exceed 1 mm IN 100 mm, noncumulative over 250 mm
- Material: black static dissipative polystyrene
- All dimensions are in mm (unless otherwise specified)
- Thickness: 0.30 ± 0.05 mm
- MSL1 260°C (IR and Convection) PbF Reflow Compatible

REVISION HISTORY

Changes from Revision Original (August 2009) to Revision A	Page
• Deleted environmental bullets from features list	1
• Deleted package marking at end of data sheet	7

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD16407Q5	ACTIVE	VSON-CLIP	DQH	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD16407	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com